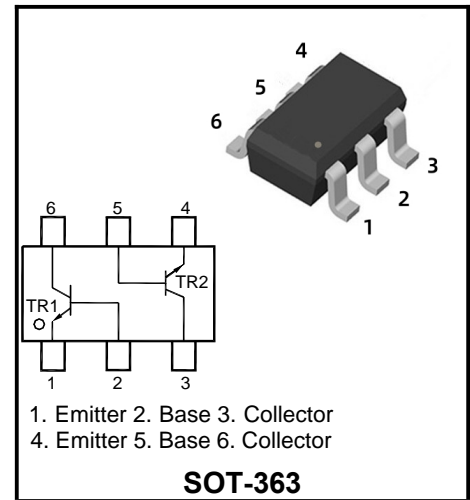


NPN Silicon General Purpose Double Transistor

for switching and amplifier applications.

Marking Code	
MMDT3904DW	K6 N



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	60	V
Collector Emitter Voltage	V_{CEO}	40	V
Emitter Base Voltage	V_{EBO}	6	V
Collector Current	I_C	200	mA
Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	- 55 to + 150	°C

Characteristics (Ta=25°C unless otherwise specified.)

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain				
at $V_{CE} = 1\text{ V}$, $I_C = 0.1\text{ mA}$	h_{FE}	40	-	-
at $V_{CE} = 1\text{ V}$, $I_C = 1\text{ mA}$	h_{FE}	70	-	-
at $V_{CE} = 1\text{ V}$, $I_C = 10\text{ mA}$	h_{FE}	100	300	-
at $V_{CE} = 1\text{ V}$, $I_C = 50\text{ mA}$	h_{FE}	60	-	-
at $V_{CE} = 1\text{ V}$, $I_C = 100\text{ mA}$	h_{FE}	30	-	-
Collector Base Cutoff Current at $V_{CE} = 30\text{ V}$	I_{CES}	-	50	nA
Emitter Base Cutoff Current at $V_{EB} = 3\text{ V}$	I_{EBO}	-	50	nA
Collector Base Breakdown Voltage at $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CBO}$	60	-	V
Collector Emitter Breakdown Voltage at $I_C = 1\text{ mA}$	$V_{(BR)CEO}$	40	-	V
Emitter Base Breakdown Voltage at $I_E = 10\text{ }\mu\text{A}$	$V_{(BR)EBO}$	6	-	V
Collector Emitter Saturation Voltage at $I_C = 10\text{ mA}$, $I_B = 1\text{ mA}$	$V_{CE(sat)}$	-	0.2	V
at $I_C = 50\text{ mA}$, $I_B = 5\text{ mA}$	$V_{CE(sat)}$	-	0.3	V
Base Emitter Saturation Voltage at $I_C = 10\text{ mA}$, $I_B = 1\text{ mA}$	$V_{BE(sat)}$	0.65	0.85	V
at $I_C = 50\text{ mA}$, $I_B = 5\text{ mA}$	$V_{BE(sat)}$	-	0.95	V
Current Gain Bandwidth Product at $V_{CE} = 20\text{ V}$, $-I_E = 10\text{ mA}$, $f = 100\text{ MHz}$	f_T	300	-	MHz
Collector Output Capacitance at $V_{CB} = 10\text{ V}$, $f = 100\text{ MHz}$	C_{ob}	-	4	pF
Delay Time at $V_{CC} = 3\text{ V}$, $V_{BE(OFF)} = 0.5\text{ V}$, $I_C = 10\text{ mA}$, $I_{B1} = 1\text{ mA}$	t_d	-	35	ns
Rise Time at $V_{CC} = 3\text{ V}$, $V_{BE(OFF)} = 0.5\text{ V}$, $I_C = 10\text{ mA}$, $I_{B1} = 1\text{ mA}$	t_r	-	35	ns
Storage Time at $V_{CC} = 3\text{ V}$, $I_C = 10\text{ mA}$, $I_{B1} = -I_{B2} = 1\text{ mA}$	t_{stg}	-	200	ns
Fall Time at $V_{CC} = 3\text{ V}$, $I_C = 10\text{ mA}$, $I_{B1} = -I_{B2} = 1\text{ mA}$	t_f	-	50	ns

Typical Characteristics

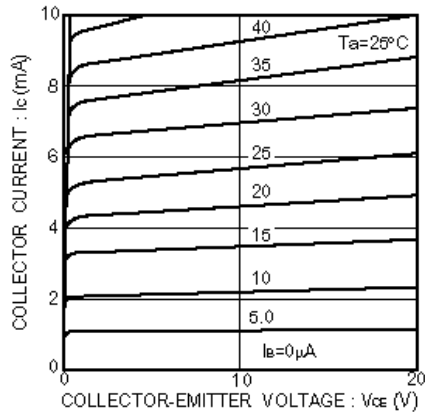


Fig.1 Grounded emitter output characteristics

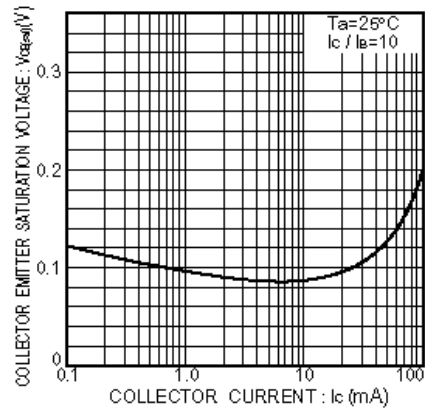


Fig.2 Collector-emitter saturation voltage vs. collector current

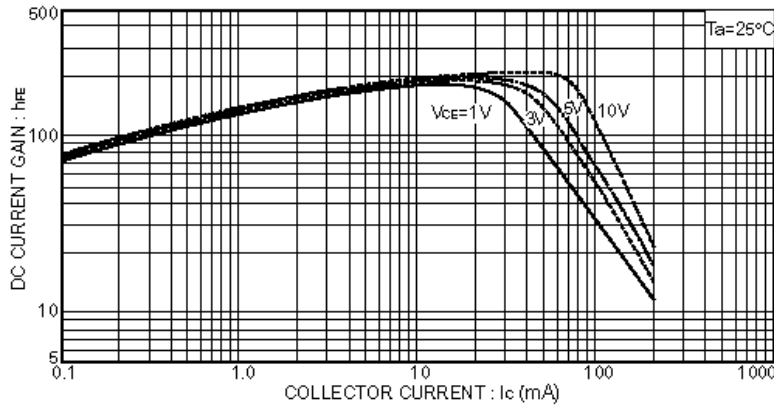


Fig.3 DC current gain vs. collector current (I)

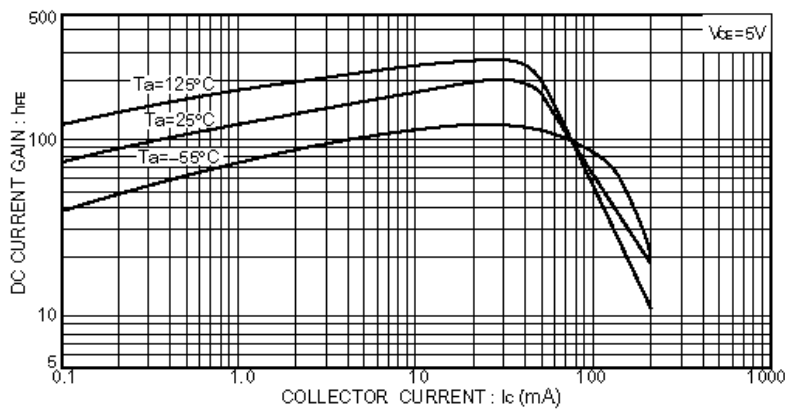


Fig.4 DC current gain vs. collector current (II)

Typical Characteristics

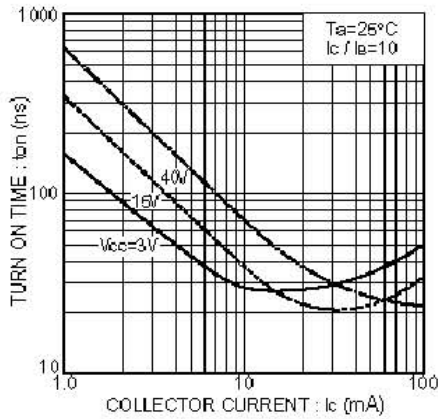


Fig.5 Turn-on time vs. collector current

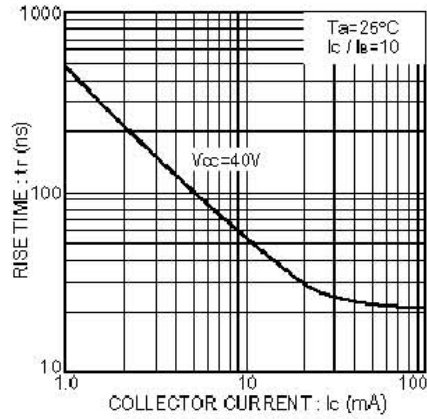


Fig.6 Rise time vs. collector current

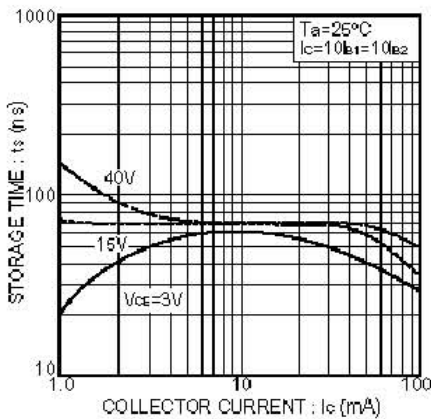


Fig.7 Storage time vs. collector current

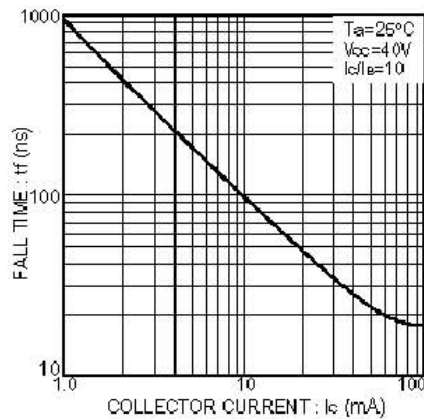


Fig.8 Fall time vs. collector current

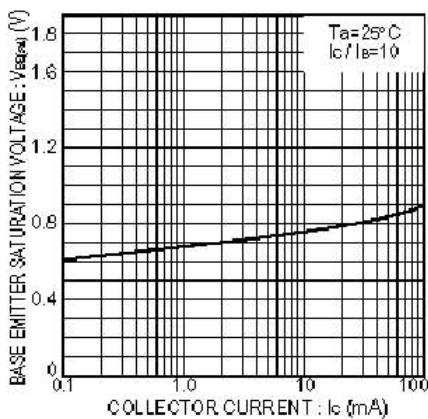


Fig.9 Base-emitter saturation voltage vs. collector current

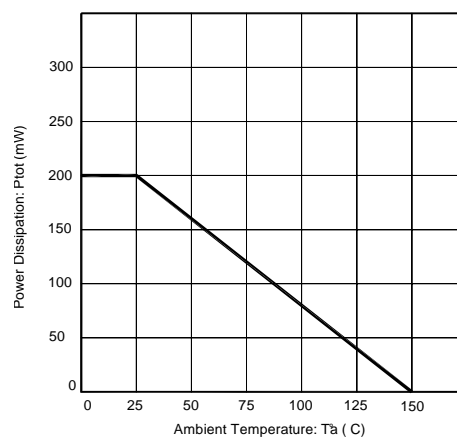


Fig.10 Power Dissipation vs Ambient Temperature

Ordering information

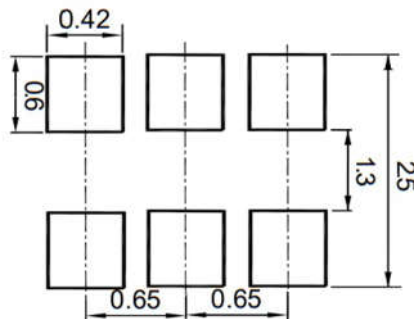
Package	Packing Description	Packing Quantity
SOT-363	Tape/Reel, 7" reel	3000PCS/Reel 120000PCS/Carton

Package Dimensions

SOT-363

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	0.8	1.1	32	43
A1	-	0.1	-	3.94
bp	0.20	0.30	7.87	11.81
c	0.10	0.25	3.94	9.84
D	1.8	2.2	70.87	86.61
E	1.15	1.35	45.28	53.15
e	1.3		51.18	
e1	0.65		25.6	
HE	2.0	2.2	78.74	86.6
Lp	0.15	0.45	5.90	17.71
Q	0.15	0.25	5.90	9.84
v	0.2		7.78	
w	0.2		7.78	
y	0.1		3.94	

The recommended mounting pad size



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